TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX08FT,TC74VCX08FK

Low-Voltage Quad 2-Input AND Gate with 3.6-V Tolerant Inputs and Outputs

The TC74VCX08FT/FK is a high-performance CMOS 2-input AND gate which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5V, 1.8V, 2.5V or 3.3V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to $3.6\ V.$

All inputs are equipped with protection circuits against static discharge.

Features (Note)

- Low-voltage operation: $V_{CC} = 1.2 \sim 3.6 \text{ V}$
- High-speed operation: $t_{pd} = 2.8 \text{ ns (max) (V}_{CC} = 3.0 \sim 3.6 \text{ V})$

 $t_{pd} = 3.7 \text{ ns (max) (VCC} = 2.3 \sim 2.7 \text{ V)}$

 $t_{pd} = 7.4 \text{ ns (max) (VCC} = 1.65 \sim 1.95 \text{ V})$

 $t_{pd} = 14.8 \text{ ns (max) (VCC} = 1.4 \sim 1.6 \text{ V})$

 $t_{pd} = 37.0 \text{ ns (max) (VCC} = 1.2 \text{ V)}$

• Output current: I_{OH}/I_{OL} = ±24 mA (min) (V_{CC} = 3.0 V)

 $: I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

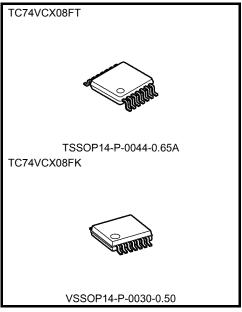
 $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min) (V}_{CC} = 1.65 \text{ V)}$

 $: I_{OH}/I_{OL} = \pm 2 \text{ mA (min) (V}_{CC} = 1.4 \text{ V)}$

- Latch-up performance: –300 mA
- ESD performance: Machine model $\geq \pm 200 \text{ V}$

Human body model $\geq \pm 2000 \text{ V}$

- Package: TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs



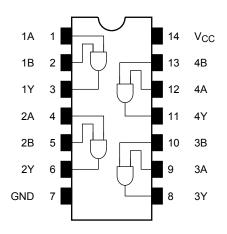
Weight

TSSOP14-P-0044-0.65A : 0.06 g (typ.) VSSOP14-P-0030-0.50 : 0.02 g (typ.)

Note: Electrical Characteristics of Vcc=1.5±0.1V and 1.2V apply only to products whose Lot Code is over "3 12" .

2007-10-19

Pin Assignment (top view)



IEC Logic Symbol

1A -	1	&	3 1Y
1B -	2		
2A -	4		6 0
2B -	5		2Y
3A -	9		8 21/
3B -	10		3Y
4A -	12		
4B -	13		11 4Y
TD			

Truth Table

Inp	uts	Outputs
Α	В	Υ
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5~4.6	V	
DC input voltage	V _{IN}	-0.5~4.6	V	
DC output voltage	V	-0.5~4.6 (Note 2)	V	
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5(Note 3)		
Input diode current	I _{IK}	-50	mA	
Output diode current	lok	±50 (Note 4)	mA	
DC output current	lout	±50	mA	
Power dissipation	PD	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	−65~150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $V_{CC} = 0 V$

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

TOSHIBA

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	1.2~3.6	V	
Input voltage	V _{IN}	-0.3~3.6	V	
Output voltage	Vour	0~3.6 (Note 2)	V	
Output voltage	V _{OUT}	0~V _{CC} (Note 3)]	
		±24 (Note 4)		
Output current	I _{OH} /I _{OI}	±18 (Note 5)	mA	
Output current	IOH/IOL	±6 (Note 6)	ША	
		±2 (Note 7)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note 8)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

3

- Note 2: $V_{CC} = 0 V$
- Note 3: High or low state
- Note 4: $V_{CC} = 3.0 \sim 3.6 \text{ V}$
- Note 5: $V_{CC} = 2.3 \sim 2.7 \text{ V}$
- Note 6: $V_{CC} = 1.65 \sim 1.95 \text{ V}$
- Note 7: $V_{CC} = 1.4 \sim 1.6 \text{ V}$
- Note 8: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$



Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < $V_{CC} \le 3.6$ V)

Character	ietice	Symbol	Test	Condition		Min	Max	Unit
Character	151105	Symbol	rest	Condition	V _{CC} (V)	IVIIII		Offic
Input voltage	H-level	V _{IH}	_		2.7~3.6	2.0	_	V
Input voltage Output voltage Input leakage curren	L-level	V _{IL}	_		2.7~3.6	_	0.8	V
				$I_{OH} = -100 \mu A$	2.7~3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}	$V_{IN} = V_{IH}$	I _{OH} = -12 mA	2.7	2.2	_	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	V
				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	
			$I_{OL} = 100 \mu A$	2.7~3.6	_	0.2		
	L-level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 12 mA	2.7	_	0.4	
	L-level	VOL		$I_{OL} = 18 \text{ mA}$	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage curre	ent	I _{IN}	V _{IN} = 0 to 3.6 V		2.7~3.6	_	±5.0	μΑ
Power-off leakage	current	loff	V_{IN} , $V_{OUT} = 0$ to 3.6 \	/	0	_	10.0	μΑ
Quiescent supply current		loo	$V_{IN} = V_{CC}$ or GND	•	2.7~3.6	_	20.0	
		Icc	$V_{CC} \leqq V_{IN} \leqq 3.6 \ V$	·	2.7~3.6	_	±20.0	μΑ
Increase in I _{CC} per	input	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7~3.6	_	750	

DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteri	etice	Symbol	Test (Condition	_	Min	Max	Unit
Onaracteri	31103	Oymbor	1031	Soriation	V _{CC} (V)	IVIIII	IVIGA	Offic
Input voltage	H-level	V _{IH}	_		2.3~2.7	1.6	_	V
input voitage	L-level	V _{IL}	_		2.3~2.7		0.7	V
H-level				I _{OH} = -100 μA	2.3~2.7	V _{CC} - 0.2		
	H-level	H-level V _{OH}	H VIN = VIH	I _{OH} = -6 mA	2.3	2.0	_	V
				I _{OH} = -12 mA	2.3	1.8	_	
Output voltage				$I_{OH} = -18 \text{ mA}$	2.3	1.7	_	
			V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.3~2.7	_	0.2	
	L-level	V _{OL}		$I_{OL} = 12 \text{ mA}$	2.3	_	0.4	
				$I_{OL} = 18 \text{ mA}$	2.3	_	0.6	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		2.3~2.7		±5.0	μΑ
Power off leakage current I _{OFF}		loff	V _{IN} , V _{OUT} = 0 to 3.6 V		0		10.0	μΑ
Quiescent supply co	ırrent	Icc	V _{IN} = V _{CC} or GND		2.3~2.7		20.0	μА
Quiescent supply co	arrent	100	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$			±20.0	μΑ



DC Characteristics (Ta = -40 to 85°C, 1.65 V \leq V_CC < 2.3 V)

Characteri	stics	Symbol	Test Co	ondition	T	Min	Max	Unit	
Gridiadion	01100	Cymbol	1001 01	1001 0011 <u>0</u> 111011		14	Max	J	
Input voltage	H-level	V _{IH}	_		1.65~2.3	0.65 × V _{CC}	_	V	
	L-level	V _{IL}	_		1.65~2.3	_	0.2 × V _{CC}	V	
Output voltage	H-level	el V _{OH}	V _{OH} V _{IN} = V _{IH}	V _{IN} = V _{IH}	I _{OH} = -100 μA	1.65~2.3	V _{CC} - 0.2	_	
				I _{OH} = -6 mA	1.65	1.25	_	V	
	L-level	I laval V	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.65~2.3	_	0.2		
	L-level	V _{OL}		I _{OL} = 6 mA	1.65	_	0.3		
Input leakage curre	nt	I _{IN}	V _{IN} = 0 to 3.6 V		1.65~2.3	_	±5.0	μА	
Power-off leakage of	current	l _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V		0	_	10.0	μА	
O de constitución de la compania		laa	V _{IN} = V _{CC} or GND		1.65~2.3	_	20.0	^	
Quiescent supply co		Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		_	±20.0	μА	

DC Characteristics (Ta = -40 to 85°C, 1.4 V \leq V_{CC} < 1.65 V)

Characteri	stics	Symbol	Test Co	andition		Min	Max	Unit
Ondradiens	51100	Cymbol	1031 00	mandon	V _{CC} (V)	141111	Wax	Offic
Input voltage	H-level	V _{IH}	_		1.4~1.65	0.65 × V _{CC}		V
	L-level	V _{IL}	_		1.4~1.65	_	0.05 × V _{CC}	V
	H-level	V _{OH}	V _{OH} V _{IN} = V _{IH}	$I_{OH} = -100 \mu A$	1.4~1.65	V _{CC} - 0.2	_	V
Output voltage				$I_{OH} = -2 \text{ mA}$	1.4	1.05	_	
	L-level	V _{OL}	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	I _{OL} = 100 μA	1.4~1.65		0.05	
	L-level	VOL	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 2 mA	1.4	_	0.35	
Input leakage curre	nt	I _{IN}	V _{IN} = 0 to 3.6 V		1.4~1.65	_	±5.0	μА
Power-off leakage current I _{OI}		l _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μА
Quiescent supply cu	ırront	loo	V _{IN} = V _{CC} or GND		1.4~1.65	_	20.0	^
Quiescent supply co	ai i Ci i i	Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$			±20.0	μА



DC Characteristics (Ta = -40 to 85° C, $1.2 \text{ V} \leq \text{V}_{CC} < 1.4 \text{ V})$

Characteristics S		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
H-level V _{IH} —		_		0.8 × V _{CC}	_	V		
Input voltage	L-level	V _{IL}	_		1.2~1.4		0.05 × V _{CC}	V
Output voltage	H-level	V _{OH}	$V_{IN} = V_{IH}$	$I_{OH} = -100 \mu A$	1.2	V _{CC} - 0.1	_	V
	L-level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \mu A$	1.2		0.05	
Input leakage currer	nt	I _{IN}	V _{IN} = 0 to 3.6 V		1.2		±5.0	μΑ
Power-off leakage c	urrent	I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0		10.0	μΑ
Quiescent supply current		loo	V _{IN} = V _{CC} or GND		1.2		20.0	μА
Quiescent supply co	ment	ICC	$V_{CC} \leqq V_{IN} \leqq 3.6 \text{ V}$		1.2	_	±20.0	μΑ

AC Characteristics (Ta = -40 to 85° C, input: $t_r = t_f = 2.0$ ns) (Note 1)

Characteristics	Symbol	Test	Test Condition V _{CC} (V)			Max	Unit
		Figure 1, Figure 2	$C_L = 15 \text{ pF}, R_L = 2 \text{ k}\Omega$	1.2	1.5	37.0	
	4		OL = 15 pr, RL = 2 KΩ	1.5 ± 0.1	1.0	14.8	
Propagation delay time	t _{pLH}			1.8 ± 0.15	1.5	7.4	ns
	φн∟		$C_L = 30$ pF, $R_L = 500$ Ω	2.5 ± 0.2	8.0	3.7	
				3.3 ± 0.3	0.6	2.8	
			$C_L = 15 \text{ pF}, R_L = 2 \text{ k}\Omega$	1.2	_	1.5	
				1.5 ± 0.1	_	1.5	
Output to output skew	t _{osLH}	(Note 2)		1.8 ± 0.15		0.5	ns
	USHL		$C_L = 30 \text{ pF}, R_L = 500 \Omega$	2.5 ± 0.2	_	0.5	
				3.3 ± 0.3	_	0.5	

Note 1: For $C_L = 50 \ pF$, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, \, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$



Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note) 1.8	0.25	
	V _{OLP}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note) 2.5	0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	3.3	0.8	
	V _{OLV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	1.8	-0.25	
Quiet output minimum dynamic $V_{\mbox{OL}}$		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	2.5	-0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	3.3	-0.8	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	1.8	1.5	
Quiet output minimum dynamic V _{OH}	V _{OHV}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note) 2.5	1.9	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note) 3.3	2.2	

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

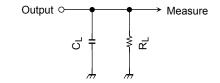
Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_		1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C_{PD}	f _{IN} = 10 MHz	(Note)	1.8, 2.5, 3.3	20	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$

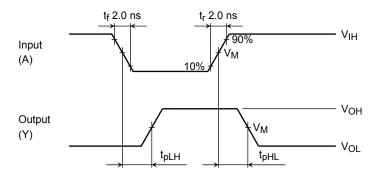
AC Test Circuit



Symbol	Vcc		
	$\begin{array}{c} 3.3 \pm 0.3 \text{ V} \\ 2.5 \pm 0.2 \text{ V} \\ 1.8 \pm 0.15 \text{ V} \end{array}$	1.5 ± 0.1 V 1.2V	
R_L	500 Ω	2 kΩ	
CL	30 pF	15 pF	

Figure 1

AC Waveform



Symbol	V _{CC}					
	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2\textrm{V}$	1.8 ± 0.15 V	$1.5\pm0.1~\textrm{V}$	1.2 V	
V_{IH}	2.7 V	V _{CC}	V _{CC}	V _{CC}	V _{CC}	
V _M	1.5 V	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	

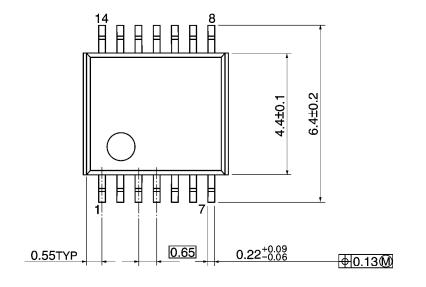
Figure 2 t_{pLH}, t_{pHL}

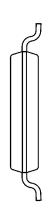
8

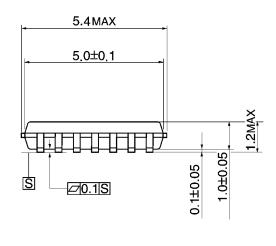
Package Dimensions

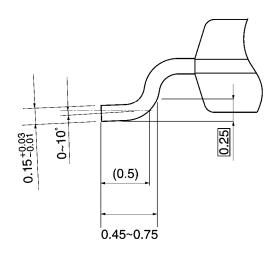
TSSOP14-P-0044-0.65A

Unit: mm







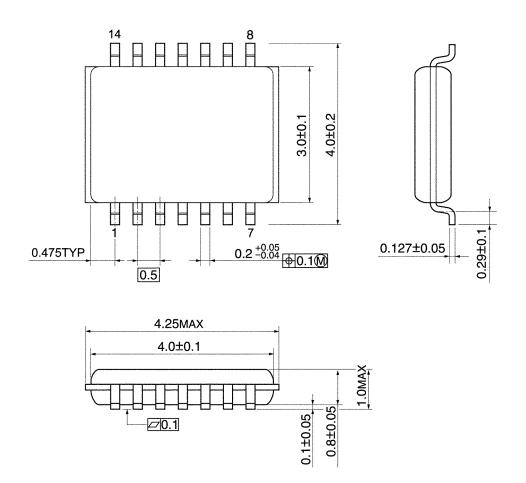


Weight: 0.06 g (typ.)

<u>TOSHIBA</u>

Package Dimensions

VSSOP14-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

RESTRICTIONS ON PRODUCT USE

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before creating and producing designs and using, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application that Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- Product is intended for use in general electronics applications (e.g., computers, personal equipment, office equipment, measuring equipment, industrial robots and home electronics appliances) or for specific applications as expressly stated in this document. Product is neither intended nor warranted for use in equipment or systems that require extraordinarily high levels of quality and/or reliability and/or a malfunction or failure of which may cause loss of human life, bodily injury, serious property damage or serious public impact ("Unintended Use"). Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. Do not use Product for Unintended Use unless specifically permitted in this document.
- . Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
 WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
 LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
 LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
 SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
 FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without
 limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile
 technology products (mass destruction weapons). Product and related software and technology may be controlled under the
 Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product
 or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
 Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA assumes no liability for damages or losses occurring as a result of noncompliance with applicable laws and regulations.